

Isolated 1W Single Output DC/DC Converters



FEATURES

- ◆Footprint from 0.69cm²
- ◆I/O isolation voltage 1000VDC
- ◆Operating Temperature: -40°C~ + 85°C
- ◆High efficiency up to 80%
- Fully encapsulated toroidal magnetics
- Internal SMD construction
- Power density up to 0.85W/cm³

No electrolytic or tantalum capacitors

- ◆5V,9V,12V and 15V output
- No heatsink required
- Dual output from a single input rail
- ◆UL 94V-0 package material
- •No external compo nents required
- Industry standard pinout
- Power sharing on output
- MTTF up to 3.4 million hours

MODEL SELECTION <u>B⁰05[©]05[®]X[®] N1[®]S[®]</u>

① Product Series② Input Voltage③ Output Voltage④ Fixed Input⑤ N1 layout(face:+Vin,-Vin,+Vout,-Vout)⑥ SIP Package

APPLICATIONS

The B-XN1S series of DC/DC converters is particularly suited to isolating and/or converting DC power rails. The galvanic isolation allows the device to be configured to provide an isolated negative rail in systems where only positive rails exist. The wide temperature range guarantees startup from -40°C and full 1 watt output at 85°C.

For lower ripple, refer to output ripple reduction section.



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SELEC	TION G	UIDE					
Order code	Input Voltage (V)	Output Voltage (V)	Output Current (MA)	Input Current (Rated Load) (MA)	Efficiency (%)	Isolation Capacitance (PF)	MTTF ¹ (KHRS)
B0505XN1S	5	5	200	289	69	30	3415
B0509XN1S	5	9	111	260	77	37	3078
B0512XN1S	5	12	83	256	78	33	2205
B0515XN1S	5	15	66	250	80	40	1532
B0524XN1S	5	24	42	248	80	48	900
B1205XN1S	12	5	200	120	69	33	2493
B1209XN1S	12	9	111	116	74	48	2311
B1212XN1S	12	12	83	110	76	55	1780
B1215XN1S	12	15	66	111	75	52	1313
B2405XN1S	24	5	200	60	70	40	201
B2409XN1S	24	9	111	55	75	59	185
B2412XN1S	24	12	83	52	80	78	163
B2415XN1S	24	15	66	52	80	79	136
B4805XN1S	48	5	200	30	70	32	213
B4809XN1S	48	9	111	28	75	50	194
B4812XN1S	48	12	83	26	80	76	164
B4815XN1S	48	15	66	26	80	75	140

1. Calculated using MIL-HDBK-217F with nominal input voltage at full load.

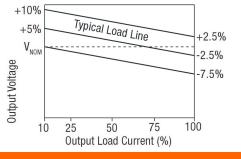
All specifications typical at TA=25°C, nominal input voltage and rated output current unless otherwise specified

Input Characteristics						
Parameter	Conditions	Min.	Typ.	Max.	Units	
	Continuous operation,5V input	4.5	5	5.5	VDC	
	Continuous operation,12V input	10.8	12	13.2	VDC	
Voltage range	Continuous operation, 15V input	13.5	15	16.5	VDC	
	Continuous operation,24V input	21.6	24	26.4	VDC	
	Continuous operation,48V input	43.2	48	52.8	VDC	
Reflected ripple current			20	40	mA p-p	

Absolute Maximum Ratings					
Parameter	Conditions				
Lead temperature 1.5mm from case for 10 seconds	300°C				
Internal power dissipation	700mW				
Input voltage V , B05 types	7V				
Input voltage Vin, B12 types	15V				
Input voltage Vin, B15 types	18V				
Input voltage Vin, B24 types	28V				
Input voltage Vin, B48 types	54V				
uiries Email:tech@microdc.on Tel:0086.20.86000646 Dage 1.of 5					



Parameter		Conditions		Min.	Typ.	Max.	Unit
Rated Power		TA= -40°C to 120°C				1.0	w
Rated Power(B24、B48)		TA=0°C to 70°C				1.0	w
oltage Set Point Accuracy	,	See tolerance envelope					
Line regulation		High VIN to low VIN			1.0	1.2	%%
ine regulation(B24、B48)		High VIN to low VIN				1.2	%%
bad regulation(B24、B48	,	10% load to rated load, 5V output types				15	%
	10% load to rated load,all other output types					10	%
oad regulation(5Vinput、		10% load to rated load, 5V output types			10	12.5	%
12Vinput)	10% load to rated load, 9V output types				9	10	%
. ,		10% load to rated load, 12V output types			6.5	7.5	%
		10% load to rated load,15V output types			6	7.0	%
oad regulation(15V input)		10% load to rated load, 5V output types			5.5	10	%
		10% load to rated load, 12V output types			2.6	3.0	%
		10% load to rated load, 15V output types			2.3	3.0	%
Ripple & Noise(B24、B48)		BW=DC to 20MHz, all input types				150	mV p-
		BW=DC to 20MHz, 5V output types			10	20	mV p-
Ripple & Noise		BW=DC to 20MHz, 9V output types			7	15	mV p-
		BW=DC to 20MHz, 12V output types			7.5	15	mV p-
		BW=DC to 20MHz, 15V output types			8	15	mV p⋅
Isolation Cha	racteristics						
Paramet	er	Conditions	Min.	Тур). Maj	x	Units
Isolation vo		Flash tested for 1 second	1000				VDC
Resistan		Viso= 1000VDC	1000	10			GΩ
Resistance(B2		Viso= 500VDC	10				GΩ
eneral Charact	aristics	· · · ·		·	·	· ·	
	ensues						
Paramet	er	Conditions	Min.	Tvr		х.	Units
Switching fro		5V input types		11			kHz
Switching free	luency	12V input types		14			kHz
		15V input types		90			kHz
Switching frequenc		All input types		10	0		kHz
Temperature	Characterist	ics					
Parameter		Conditions		Min.	Typ.	Max.	Uni
Specification		B05、B12、B15		-40		85	°C
Specification		B24、B48		0		70	°C
		B05、B12、B15				130	°C
Storage						150	°C
Storage Storage		B24、B48		-55			°C
				-55	33		
Storage ase temperature rise		B24、B48		-55	33 28		
Storage ase temperature rise above		B24、B48 0505,1205		-55			°C
Storage ase temperature rise		B24、B48 0505,1205 0509,0512,0515,1209,1212,1215		-55	28		°C °C
Storage ase temperature rise above		B24、B48 0505,1205 0509,0512,0515,1209,1212,1215 1505		-55	28 26		°C °C
Storage ase temperature rise above ambient Cooling	rating graph	B24、B48 0505,1205 0509,0512,0515,1209,1212,1215 1505 1512,1515 Free air convection			28 26 17	velope	°C °C
Storage ase temperature rise above ambient Cooling emperature de	rating graph	B24、B48 0505,1205 0509,0512,0515,1209,1212,1215 1505 1512,1515 Free air convection			28 26	velope	°C °C
Storage ase temperature rise above ambient Cooling	rating graph	B24、B48 0505,1205 0509,0512,0515,1209,1212,1215 1505 1512,1515 Free air convection		Tol e	28 26 17 erance en		°C °C
Storage ase temperature rise above ambient Cooling emperature de 1.5		B24、B48 0505,1205 0509,0512,0515,1209,1212,1215 1505 1512,1515 Free air convection		Tol e	28 26 17		°C °C
Storage ase temperature rise above ambient Cooling emperature de 1.5	erating graph	B24、B48 0505,1205 0509,0512,0515,1209,1212,1215 1505 1512,1515 Free air convection		Tole	28 26 17		° <u>c</u> ° <u>c</u> °c
Storage ase temperature rise above ambient Cooling emperature de 1.5		B24、B48 0505,1205 0509,0512,0515,1209,1212,1215 1505 1512,1515 Free air convection 5V & 12V Inpu Ø 24V & 48V Inpu		Tol e	28 26 17		2° 2° 2°
Storage ase temperature rise above ambient Cooling emperature de 1.5	85°C	B24、B48 0505,1205 0509,0512,0515,1209,1212,1215 1505 1512,1515 Free air convection 5V & 12V Inpu Ø 24V & 48V Inpu		Tole	28 26 17		+2.5% -2.5%
Storage ase temperature rise above ambient Cooling	85°C	B24、B48 0505,1205 0509,0512,0515,1209,1212,1215 1505 1512,1515 Free air convection 5V & 12V Inpu Ø 24V & 48V Inpu		Tole	28 26 17		<u>°c</u> <u>°c</u> °c



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Ambient Temperature (°C)

-40



Technical notes

ISOLATION VOLTAGE

"Hi Pot Test","Flash Tested","Withstand Voltage","Dielectric Withstand Voltage"&" Isolation Test Voltage" are all terms that relate to the same thing, a test voltage Applied for a specified time, across a component designed to provide electrical isolation, to verify the integrity of that isolation. Professional Power Module B series of DC/DC converters are all 100% production tested at their stated isolation voltage. This is 1KVDC for 1 second.

A question commonly asked is,"What is the continuous voltage that can be applied across the part in normal operation?"

For a part holding no specific agency approvals, such as the B series ,both input and output should normally be maintained within SELV limits i.e. less than 42.4V peak, or 60VDC. The isolation test voltage represents a measure of immunity to transient voltages and the part should never be used as an element of a safety isolation system. The part could be expected to function correctly with several hundred volts offset applied continuously across the isolation barrier, but then the circuitry on both sides of the barrier must be regarded as operating at an unsafe voltage and further isolation/insulation systems must form a barrier between these circuits and any user-acssible circuitry according to safety standard requirements.

REPEATED HIGH-VOLTAGE ISOLATION TESTING

It is well known that repeated high-voltage isolation testing of a barrier component can actually degrade isolation capability, to a lesser or greater degree depending on materials. Construction and environment. The B series has toroidal isolation transformers, with no additional insulation between primary and secondary windings of enameled wire. While parts can be expected to withstand several times the stated test voltage, the isolation capability does depend on the wire insulation. Any material, including this enamel (typically polyurethane) is susceptible to eventual chemical degradation when subject to very high applied voltages thus implying that the number of tests should be strictly limited. We therefore strongly advise against repeated high voltage isolation testing, but if it is absolutely required, that the voltage be reduced by 20% from specified test voltage.

This consideration equally applies to agency recognized parts for better than functional isolation where the wire enamel insulation is always supplemented by a further insulation system of physical spacing or barriers.

Technical notes

Output ripple reduction

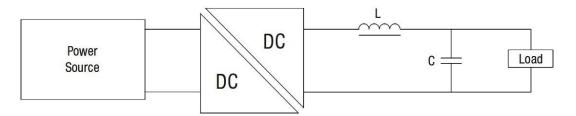
By using the values of inductance and capacitance stated, the output ripple at the rated load is lowered to 5mV p-p max.

Component selection

Capacitor: Ceramic chip capacitors are recommended. It is required that the ESR(Equivalent Series Resistance)should be as low as possible.X7R types are recommended. The voltage rating should be at least twice(except for 15V output), the rated output voltage of the DC/DC converter.

Inductor: The rated current of the inductor should not be less than of the output of the DC/DC converter. At the rated current, the DC resistance of the inductor should be

such that the voltage drop across the inductor is <2% of the rated voltage of the DC/DC converter. The SRF(Self Resonant Frequency) should be >20MHz.



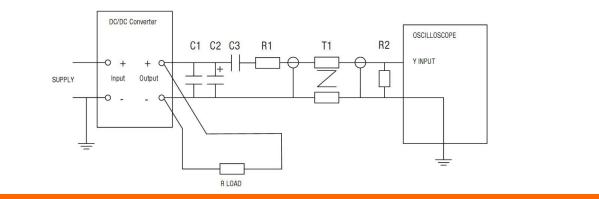
Ripple & Noise Characterisation Method

Ripple and noise measurements are performed with the following test configuration.

C1	1 µ F X7R multilayer ceramic capacitor, voltage rating to be a minimum of 3 times the output voltage of the DC/DC converter			
C2	10 µ F tantalum capacitor, voltage rating to be a minimum of 1.5 times the output voltage of the DC/DC converter with an ESR of less than 100m Q at 100 KHz			
C3	100nF multilayer ceramic capacitor, general purpose			
R1	450 Ω resistor, carbon fi Im, \pm 1% tolerance			
R2	50 Ω BNC termination			
T1	3T of the coax cable through a ferrite toroid			
RLOAD	Resistive load to the maximum power rating of the DC/DC converter. Connections should be made via twisted wires			
R3	50Ω resistor, carbon film, \pm 1%			

Measured values are multiplied by 10 to obtain the specified values.

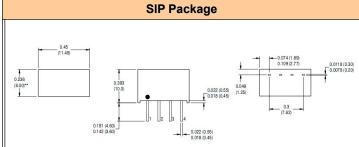
Differential Mode Noise Test Schematic





OUTLINE DIMENSIONS & FOOTPRINT DETAILS

MECHANICAL DIMENSIONS



All dimensions in inches ± 0.01 (mm ± 0.25 mm). All pins on a 0.1(2.54) pitch and within $\pm 0.01(0.25)$ of true position. Weight: 1.48g (DIP)1.30g (SIP)

FOOTPRINT DETAILS

-4 PIN SIP		
Pin	Function	
1	+Vin	
2	-Vin	
3	+Vout	
4	-Vout	

Specifcations can be changed any time without notice.

No parallel connection or plug and play.

Note:

1. The load shouldn't be less than 10%, otherwise ripple will increase dramatically.

Operation under 10% load will not damage the converter; However, they may not meet all specification listed.
 All specifications measured at Ta=25°C, humidity<75%, nominal input voltage and rated output load unless

otherwise specified. 4. In this datasheet, all the test methods of indications are based on corporate standards.

